

## DESCRIPTION

The MP5010S is a protection device designed to protect circuitry on the output (source) from transients on input ( $V_{CC}$ ). It also protects  $V_{CC}$  from undesired shorts and transients coming from the source.

At start up, inrush current is limited by limiting the slew rate at the source. The slew rate is controlled by a small capacitor at the dv/dt pin. The dv/dt pin has an internal circuit that allows the customer to float this pin (no connect) and still receive 1.1ms ramp time at the source.

The maximum load at the output (source) is current limited. This is accomplished by utilizing a sense FET topology. The magnitude of the current limit is controlled by an external resistor from the I-Limit pin to the Source pin.

An internal charge pump drives the gate of the power device, allowing a very low on-resistance DMOS power FET of just 40m $\Omega$ .

The source is protected from the  $V_{CC}$  input being too low or too high. Under Voltage Lockout (UVLO) assures that  $V_{CC}$  is above the minimum operating threshold, before the power device is turned on. If  $V_{CC}$  goes above the high output threshold, the source voltage will be limited.

## FEATURES

- Wide 3.6V-to-18V Operating Input Range
- Integrated 40m $\Omega$  Power FET
- Enable/Fault Pin
- Adjustable Slew Rate for Output Voltage
- Adjustable Current Limit
- Thermal Protection

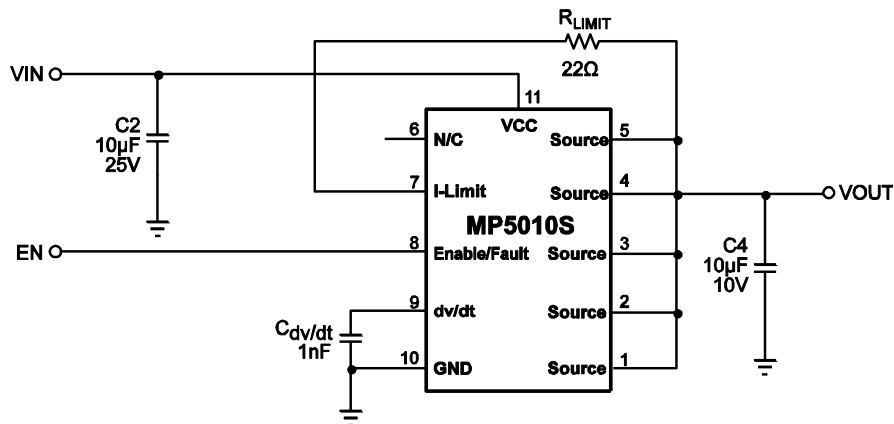
## APPLICATIONS

- Hot Swap
- Wireless Modem Data Cards
- PC Cards
- Laptops

All MPS parts are lead-free and adhere to the RoHS directive. For MPS green status, please visit MPS website under Products, Quality Assurance page.

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## TYPICAL APPLICATION



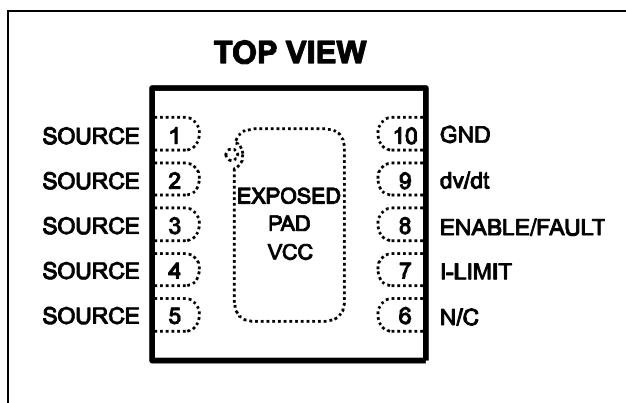
## ORDERING INFORMATION

Part Number*	Package	Top Marking
MP5010SDQ	QFN10 (3mmx3mm)	AGK

\* For Tape & Reel, add suffix –Z (e.g. MP5010SDQ–Z).

For RoHS compliant packaging, add suffix –LF (e.g. MP5010SDQ-LF-Z).

## PACKAGE REFERENCE



### ABSOLUTE MAXIMUM RATINGS <sup>(1)</sup>

$V_{CC}$ , SOURCE, I-LIMIT ..... –0.3V to 22V  
dv/dt, ENABLE/FAULT ..... –0.3V to 6V  
Storage Temperature ..... –65°C to +155°C  
Junction Temperature ..... +150°C  
Lead Temperature ..... +260°C  
Continuous Power Dissipation ( $T_A=+25^\circ\text{C}$ ) <sup>(2)</sup>  
..... 2.5W

### Recommended Operating Conditions <sup>(3)</sup>

Input Voltage Operating Range ..... 4V to 18V  
Continuous Current  
0.5 in<sup>2</sup> pad,  $T_A=25^\circ\text{C}$  ..... 4.2A  
For Minimum Copper,  $T_A=80^\circ\text{C}$  ..... 2.3A  
Operating Junction Temp. ( $T_J$ ) ..... –40°C to +125°C

### Thermal Resistance <sup>(4)</sup> $\theta_{JA}$ $\theta_{JC}$

QFN10 (3mmx3mm) ..... 50 ..... 12 ... °C/W

#### Notes:

- Exceeding these ratings may damage the device.
- The maximum allowable power dissipation is a function of the maximum junction temperature  $T_J(\text{MAX})$ , the junction-to-ambient thermal resistance  $\theta_{JA}$ , and the ambient temperature  $T_A$ , the maximum allowable power dissipation at any ambient temperature is calculated using:  $P_D(\text{MAX})=(T_J(\text{MAX})-T_A)/\theta_{JA}$ . Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage. Reduce 0.2 Watts for every 10°C ambient temperature increasing
- The device is not guaranteed to function outside of its operating conditions.
- Measured on JESD51-7 4-layer board.

## ELECTRICAL CHARACTERISTICS

$V_{CC} = 5V$ ,  $R_{LIMIT}=22\Omega$ , Capacitive Load= 10 $\mu$ F,  $T_A=25^\circ C$ , unless otherwise noted.

Parameters	Symbol	Condition	Min	Typ	Max	Units
<b>Power FET</b>						
Delay Time <sup>(5)</sup>	$t_{DLY}$	Enabling of chip to $I_D=40mA$ with a 5 $\Omega$ resistive load		0.2		ms
ON Resistance	$R_{DSon}$	$T_J=25^\circ C$		40	55	m $\Omega$
		$T_J=85^\circ C$ <sup>(6)</sup>		52		
Off State Output Voltage	$V_{OFF}$	$V_{CC}=18V$ , $V_{EN}=0V$ , $R_L=500\Omega$			120	mV
<b>Thermal Latch</b>						
Shutdown Temperature <sup>(6)</sup>	$T_{SD}$			175		$^\circ C$
<b>Under/Over Voltage Protection</b>						
Output Clamping Voltage	$V_{CLAMP}$	Overvoltage Protection $V_{CC}=8V$	5.95	6.65	7.35	V
Under Voltage Lockout	$V_{UVLO}$	Rising Edge	3.2	3.6	4.0	V
Under Voltage Lockout (UVLO) Hysteresis	$V_{HYST}$			0.4		V
<b>Current Limit <sup>(7)</sup></b>						
Hold Current	$I_{LIM-SS}$	0 $\Omega$ Short Resistance, $R_{LIM}=22\Omega$	1.2	2	2.8	A
Trip Current	$I_{LIM-OL}$	$R_{LIM}=22\Omega$		3.1		A
<b>dv/dt Circuit</b>						
Rise Time <sup>(8)</sup>	$T_r$	Float dv/dt pin	0.4	1.1	2.6	ms
<b>Enable/Fault</b>						
Low Level Input Voltage	$V_{IL}$	Output Disabled			0.5	V
Intermediate Level Input Voltage	$V_{I(INT)}$	Thermal Fault, Output Disabled	0.82	1.4	1.95	V
High Level Input Voltage	$V_{IH}$	Output Enabled	2.5			V
High State Maximum Voltage	$V_{I(MAX)}$			4.95		V
Pull Up Current (Source)	$I_{IL}$	$V_{ENABLE}=0V$	15	25	35	$\mu A$
Maximum Fanout for Fault Signal		Total number of chips that can be connected for simultaneous shutdown			3	Units
Maximum Voltage on Enable Pin <sup>(9)</sup>	$V_{MAX}$				$V_{CC}$	V
<b>Total Device</b>						
Bias Current	$I_{BIAS}$	Device Operational		815	900	$\mu A$
		Thermal Shutdown		580	650	
Minimum Operating Voltage for UVLO	$V_{MIN}$	Enable<0.5V			2.5	V

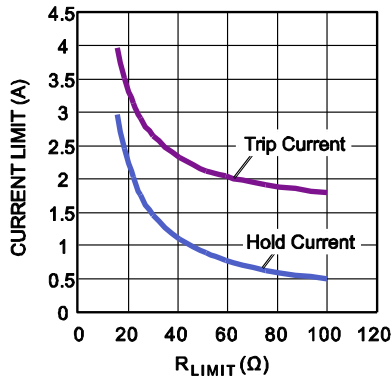
### Notes:

- 5) Related to Rise Time. See description in Fault and Enable Pin Section on Page 9.
- 6) Guaranteed by design.
- 7) Guaranteed by Characterization Test.
- 8) Measured from 10% to 90%.
- 9) Maximum Input Voltage on Enable pin to be  $\leq 6V$  if  $V_{CC} \geq 6V$ . Maximum Input Voltage on Enable pin to be  $V_{CC}$  if  $V_{CC} \leq 6V$ .

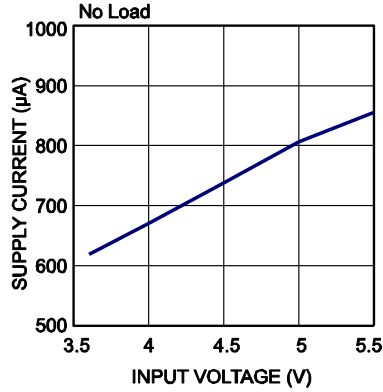
# TYPICAL PERFORMANCE CHARACTERISTICS

$V_{IN} = 5V$ ,  $V_{EN}=5V$ ,  $R_{LIMIT}=22\Omega$ ,  $C_{OUT}=10\mu F$ ,  $C_{dv}/dt = 0nF$ ,  $T_A=25^\circ C$ , unless otherwise noted.

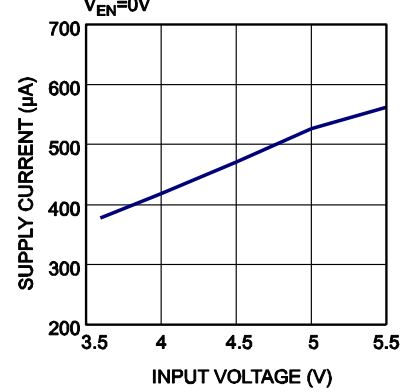
**Trip Current & Hold Current vs.  $R_{LIMIT}$**



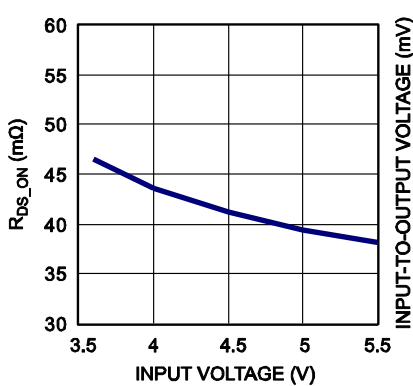
**Supply Current, Output Enabled vs. Input Voltage**



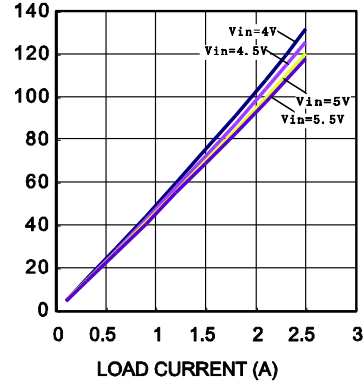
**Supply Current, Output Disabled vs. Input Voltage**



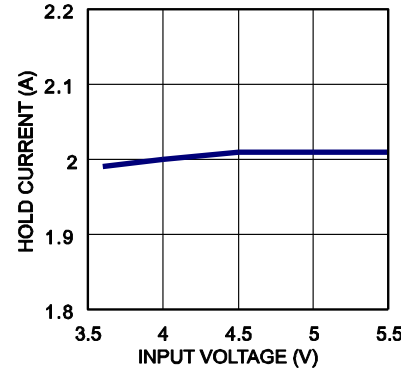
**$R_{DS\_ON}$  vs. Input Voltage**



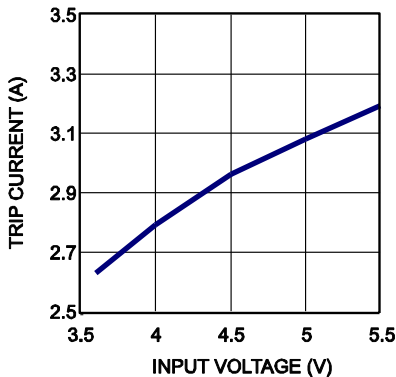
**Input-to-output Voltage vs. Load Current**



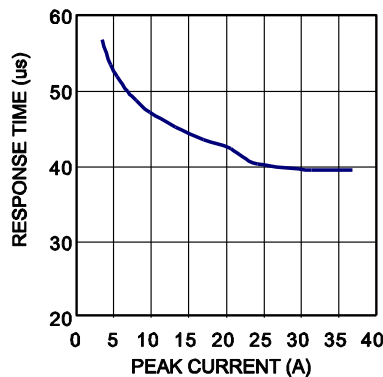
**Hold Current vs. Input Voltage**



**Trip Current vs. Input Voltage**

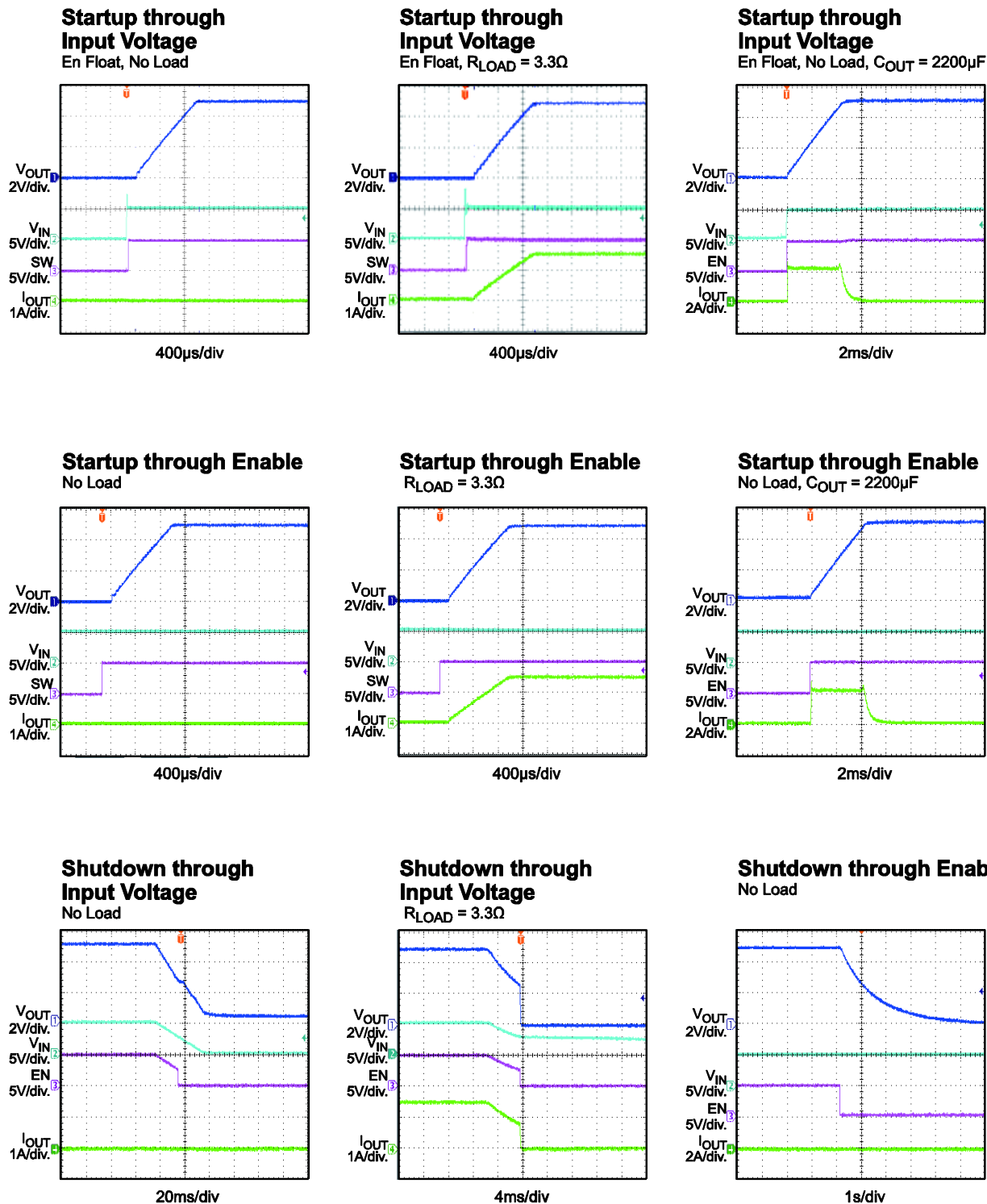


**Current Limit Response vs. Peak Current**



# TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

$V_{IN} = 5V$ ,  $V_{EN}=5V$ ,  $R_{LIMIT}=22\Omega$ ,  $C_{OUT}=10\mu F$ ,  $C_{dv}/dt = 0nF$ ,  $T_A=25^\circ C$ , unless otherwise noted.

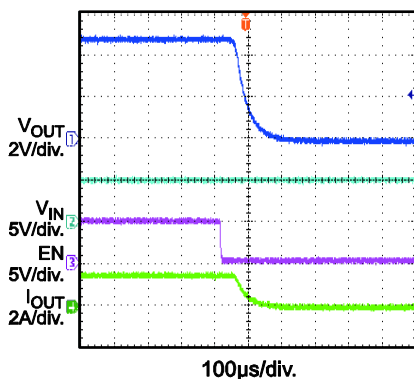


# TYPICAL PERFORMANCE CHARACTERISTICS *(continued)*

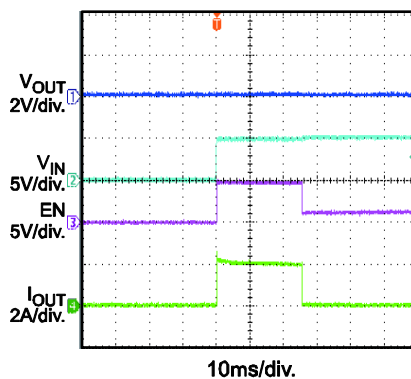
$V_{IN} = 5V$ ,  $V_{EN}=5V$ ,  $R_{LIMIT}=22\Omega$ ,  $C_{OUT}=10\mu F$ ,  $C_{dv}/dt = 0nF$ ,  $T_A=25^\circ C$ , unless otherwise noted.

## Shutdown Through Enable

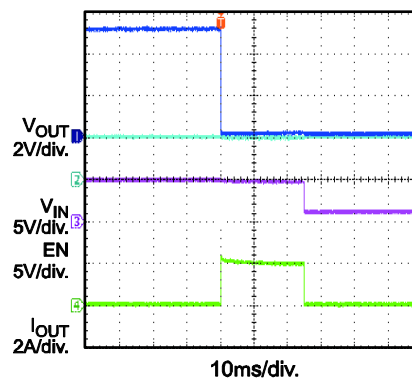
$R_{LOAD} = 3.3\Omega$



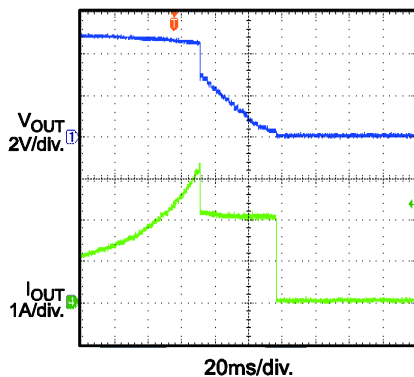
## Short Circuit before Input Voltage Startup, and Thermal Shutdown



## Short Circuit during Normal Operation, and Thermal Shutdown

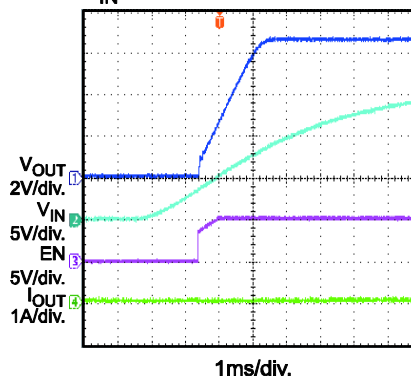


## Current Limit



## Start Up into OVP, no load EN float

$V_{IN} = 16V$



**PIN FUNCTIONS**

Pin #	Name	Description
1-5	SOURCE	This pin is the source of the internal power FET and the output terminal of the IC.
6	N/C	DO NOT CONNECT, The pin must be float.
7	I-Limit	A resistor between this pin and the Source pin sets the overload and short circuit current limit levels.
8	Enable/Fault	The Enable/Fault pin is a tri-state, bi-directional interface. It can be used to enable the output of the device by floating the pin, or disable the chip by pulling it to ground (using an open drain or open collector device). If a thermal fault occurs, the voltage on this pin will go to an intermediate state to signal a monitoring circuit that the device is in thermal shutdown.
9	dv/dt	The internal dv/dt circuit controls the slew rate of the output voltage at turn on.
10	GND	Negative Input Voltage to the Device. This is used as the internal reference for the IC.
11 (Exposed Pad)	V <sub>CC</sub>	Positive input voltage to the device.

## BLOCK DIAGRAM

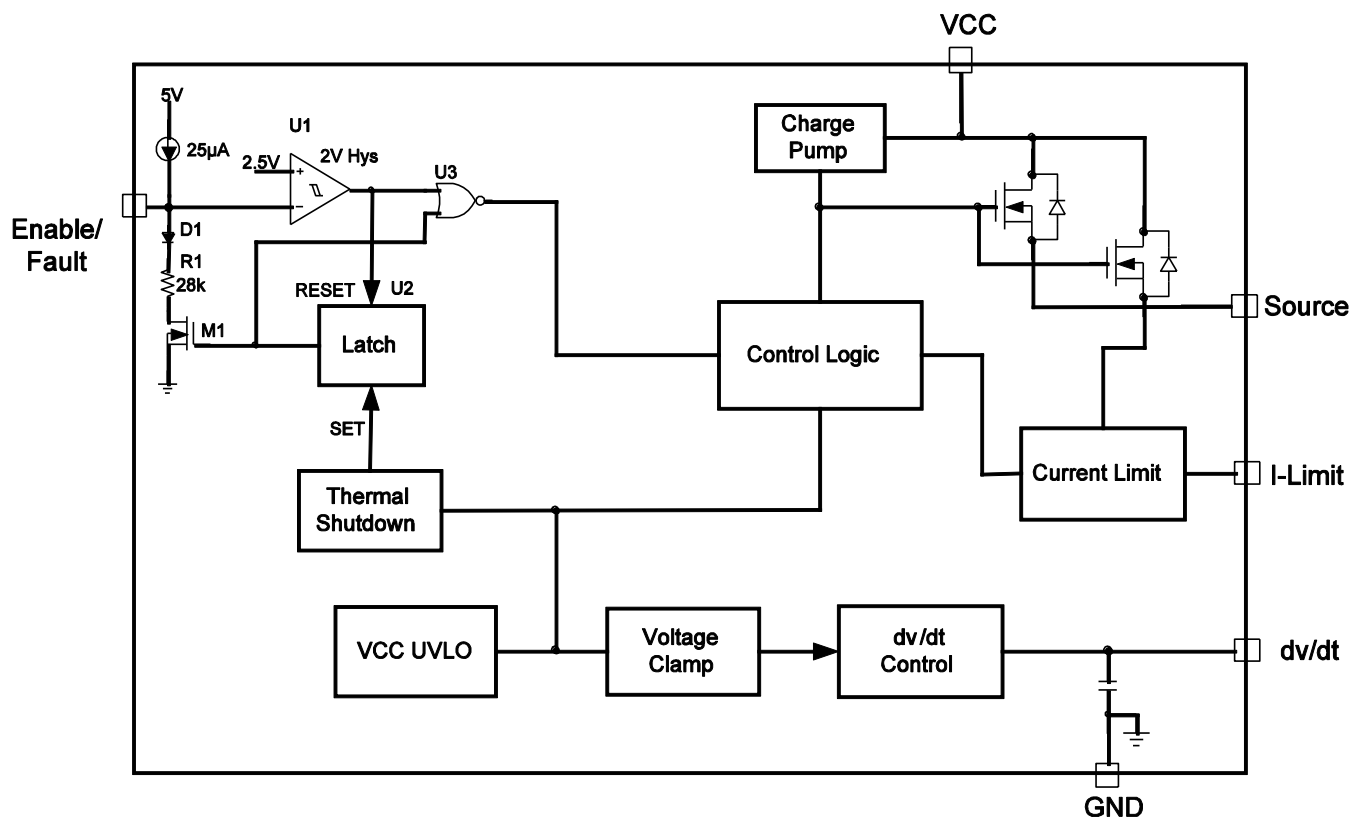


Figure 1—Functional Block Diagram



## OPERATION

The MP5010S is designed to limit the in-rush current to the load when a circuit card inserts into a live backplane power source, thereby limiting the backplane's voltage drop and the  $dV/dt$  of the voltage to the load as well. It offers an integrated solution to monitor the input voltage, output voltage, output current and die temperature which eliminates the requirement of external current sense power resistor, power MOSFET and thermal sense device.

### Under Voltage Lockout Operation

If the supply (input) is below the UVLO threshold, the output is disabled, and the EN/Fault line is driven low.

When the supply goes above the UVLO threshold, the output is enabled and the EN/Fault line is released. When the EN/Fault line is released it will be pulled high by a  $25\mu A$  current source. No external pull up resistor is required. In addition, the pull up voltage is limited to 4.95 volts.

### Output Over Voltage Protection

If the input voltage is higher than the OVP threshold, the output is clamped at 6.65V (typical) no matter what the output current is.

### Current Limit

When the part is active, if load reaches trip current (minimum threshold current triggering over current protection) or a short is present, the part switches into to a constant-current (hold current) mode. Part will be shutdown only if the over current condition stays long enough to trigger thermal protection.

However, when the part is powered up by  $V_{CC}$  or EN, the load current should be smaller than hold current. Otherwise, the part can't be fully turned on.

In a typical application using a current limit resistor of  $22\Omega$ , the trip current will be 3.1A and the hold current will be 2A. If the device is in its normal operating state and passing 1.5A it will need to dissipate only 90mW with the very low on resistance of  $40m\Omega$ . For the package dissipation of  $50^\circ C/Watt$ , the temperature rise will only be  $+9^\circ C$ . Combined with a  $25^\circ C$  ambient, this is only  $34^\circ C$  total package

temperature.

During a short circuit condition, the device now has 5V across it with constant hold current and therefore must dissipate large power. At  $50^\circ C/watt$ , if uncontrolled, the temperature would rise above the MP5010S thermal protection ( $+175^\circ C$ ) and shutdown the device to cause the temperature to drop below a hysteresis level. Proper heat sink must be used if the device is intended to supply the hold current and not shutdown. Without a heat sink, hold current should be maintained below 600mA at  $+25^\circ C$  and below 360mA at  $+85^\circ C$  to prevent the device from activating the thermal shutdown feature.

### Thermal Protection

When thermal protection is triggered, the output is disabled and the EN/Fault line is driven to the mid level. The thermal fault condition is latched (meaning the fault flag is set), and the part will remain latched off until the fault (enable) line is brought low. Cycling the power below the UVLO threshold will also reset the fault flag.

### Fault and Enable Pin

The Enable/Fault Pin is a Bi-Directional three levels I/O with a weak pull up current ( $25\mu A$  typical). The three levels are low, mid and high. It functions to enable/disable the part and to relay Fault information.

Enable pin as an input:

1. Low and mid disable the part.
2. Low, in addition to disabling the part, clears the fault flag.
3. High enables the part (if the fault flag is clear) after a delay time. The delay time equation is as below:

$$T_{\text{delay}} = 80\mu s + \frac{1}{6} t_{\text{rise}}$$

Enable pin as an output:

1. The pull up current may (if not overridden) allow a "wired nor" pull up to enable the part.

2. An under voltage will cause a low on the enable pin, and will clear the fault flag.
3. A thermal fault will cause a mid level on the enable pin, and will set the fault flag

The Enable/Fault line must be above the mid level for the output to be turned on.

The fault flag is an internal flip-flop that can be set or reset under various conditions:

1. Thermal Shutdown: set fault flag
2. Under Voltage: reset fault flag

3. Low voltage on Enable/Fault pin: reset fault flag
4. Mid voltage on Enable/Fault pin: no effect

Under a fault, the Enable/Fault pin is driven to the mid level.

There are 4 types of faults, and each fault has a direct and indirect effect on the Enable/Fault pin and the internal fault flag. In a typical application there are one or more of the MP5010S chips in a system. The Enable/Fault lines will typically be connected together.

**Table 1—Fault Function Influence in Application**

Fault description	Internal action	Effect on Fault Pin	Effect on Flag	Effect on secondary Part
Short/over current	Limit current	none	none	none
Under Voltage	Output is turned off	Internally drives Enable/Fault pin to Logic low	Flag is reset	Secondary part output is disabled, and fault flag is reset.
Over Voltage	Limit output voltage	None	None	None
Thermal Shutdown	Shutdown part. The part is latched off until a UVLO or externally driven to ground.	Internally drives Enable/Fault pin to mid level	Flag is Set	Secondary part output is disabled.

## APPLICATION INFORMATION

### Current Limit Setting

The desired current limit is a function of the external current limit resistor.

**Table 2—Current Limit vs. Current Limit Resistor**  
( $V_{CC}=5V$ )

$R_{LIMIT} (\Omega)$	15.4	22	51	100
Trip Current (A)	4	3.1	2.1	1.8
Hold Current (A)	3	2	0.9	0.5

### Rise Time Setting

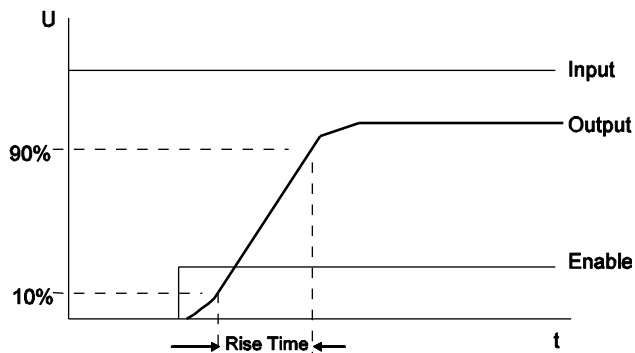
The rise time is a function of the capacitor ( $C_{dv/dt}$ ) on the  $dv/dt$  pin.

**Table 3—Rise Time vs.  $C_{dv/dt}$**

$C_{dv/dt}$	none	50pF	500pF	1nF
Rise Time (TYPICAL)(ms)	1.1	2.2	12.3	23.5

\* Notes: Rise Time =  $K_{RT} \cdot (50pF + C_{dv/dt})$ ,  $K_{RT} = 22E6$

The “rise time” is measured by from 10% to 90% of output voltage.

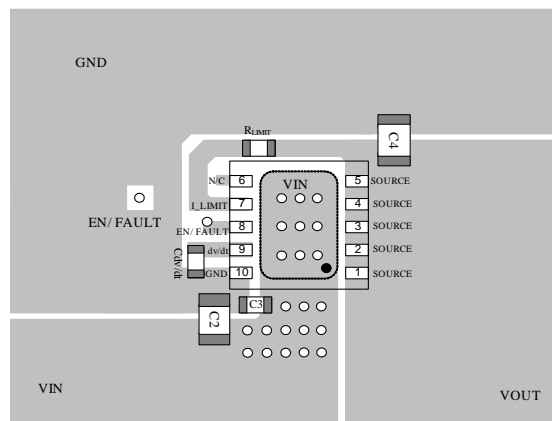


**Figure 2—Rise Time**

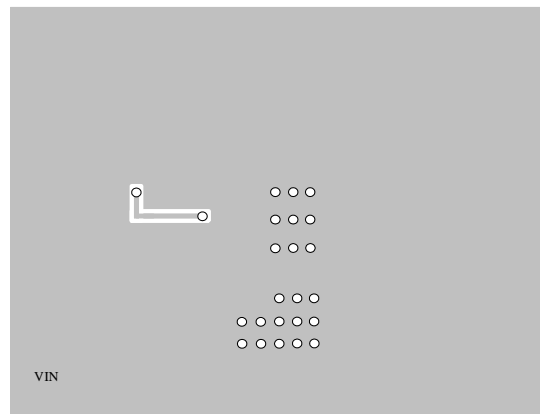
### PCB Layout

PCB layout is very important to achieve stable operation. Please follow these guidelines and take below figure for reference.

Place  $R_{LIMIT}$  close to  $I_{LIMIT}$  pin,  $C_{dv/dt}$  close to  $dv/dt$  pin and input cap close to  $V_{CC}$  pin. Keep the N/C pin float. Put vias in thermal pad and ensure enough copper area near  $V_{CC}$  and source to achieve better thermal performance.



**Top Layer**



**Bottom Layer**

**Figure 3—PCB Layout**

### Design Example

Below is a direct current sensing design example following the application guidelines for the specifications:

**Table 4—Design Example**

$V_{IN}$	5V
Trip Current	3.1A
Hold Current	2A

The detailed application schematic is shown in Figure 4. The typical performance and circuit waveforms have been shown in the Typical Performance Characteristics section. For more device applications, please refer to the related Evaluation Board Datasheets.

# TYPICAL APPLICATION CIRCUITS

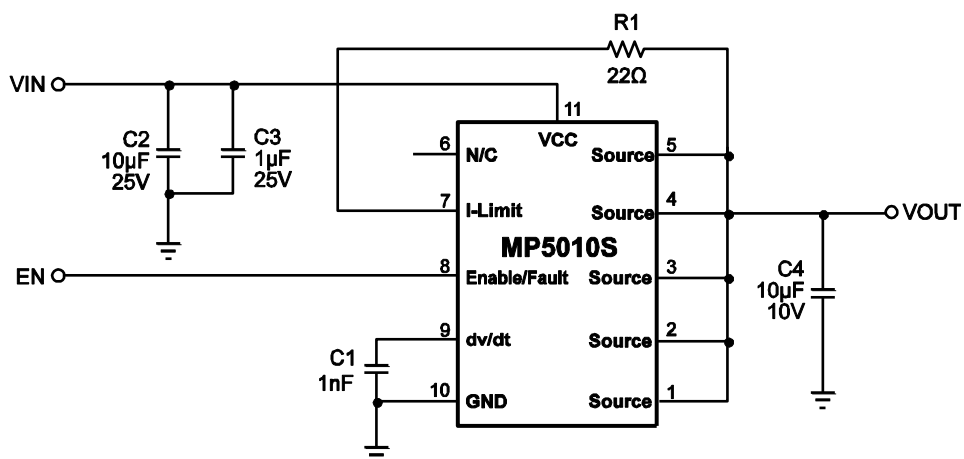
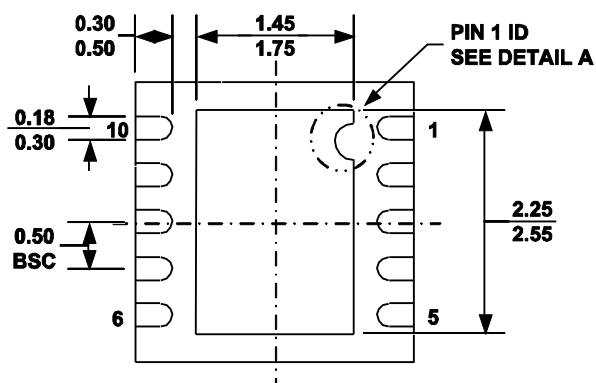
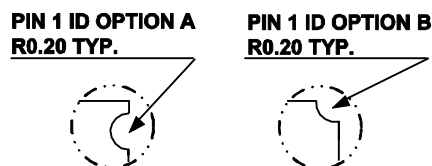


Figure 4—Application Circuit with Direct Current Sensing

### QFN10 (3mm x 3mm)



### BOTTOM VIEW



## DETAIL A



- 1) ALL DIMENSIONS ARE IN MILLIMETERS.
- 2) EXPOSED PADDLE SIZE DOES NOT INCLUDE MOLD FLASH.
- 3) LEAD COPLANARITY SHALL BE 0.10 MILLIMETER MAX.
- 4) DRAWING CONFORMS TO JEDEC MO-229, VARIATION VEED-5.
- 5) DRAWING IS NOT TO SCALE.

## RECOMMENDED LAND PATTERN

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